Contents

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{DS}	Drain-source voltage (V_{GS} = 0)	100	V
V_{GS}	Gate- source voltage	±20	V
I_D (1)	Drain current (continuous) at T_C = 25 °C	50	A
I_D	Drain current (continuous) at T_C = 100 °C	35	A
I_{DM} (2)	Drain current (pulsed)	200	A
P_{TOT}	Total dissipation at T_C = 25 °C	150	W
	Derating factor	1	W/°C
dv/dt(3)	Peak diode recovery voltage slope	27	V/ns
E_{AS} (4)	Single pulse avalanche energy	385	mJ
T_{stg}	Storage temperature	- 55 to 175	°C
T_j	Max. operating junction temperature		

1. Limited by wire bonding
2. Pulse width limited by safe operating area
3. I_{SD} ≤50 A, di/dt ≤600 A/µs, V_{DD} ≤$V_{(BR)DSS}$, T_j ≤T_{JMAX}.
4. Starting T_j= 25 °C, I_D= 50 A, V_{DD}=25 V

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{thj\text{-}case}$	Thermal resistance junction-case max	1	°C/W
$R_{thj\text{-}a}$	Thermal resistance junction-ambient max	62.5	°C/W
T_l	Maximum lead temperature for soldering purpose	300	°C

2 Electrical characteristics

(T_{CASE} = 25 °C unless otherwise specified)

Table 4. On/off states

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source Breakdown voltage	I_D = 250 µA, V_{GS} = 0	100			V
I_{DSS}	Zero gate voltage Drain current (V_{GS} = 0)	V_{DS} = Max rating V_{DS}=Max rating,T_C=125°C			1 10	µA µA
I_{GSS}	Gate-body leakage current (V_{DS} = 0)	V_{GS} = ±20 V			±100	nA
$V_{GS(th)}$	Gate threshold voltage	V_{DS} = V_{GS}, I_D = 250 µA	2	3	4	V
$R_{DS(on)}$	Static drain-source on resistance	V_{GS} = 10 V, I_D = 25 A		0.025	0.028	Ω

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
g_{fs} (1)	Forward transconductance	V_{DS} = 15 V, I_D=28 A	-	22		S
C_{iss}	Input capacitance	V_{DS} = 25 V, f = 1 MHz, V_{GS} = 0	-	2180		pF
C_{oss}	Output capacitance			298		pF
C_{rss}	Reverse transfer capacitance			83.7		pF
Q_g	Total gate charge	V_{DD} = 50 V, I_D = 40 A, V_{GS} = 10V *(see Figure 15)*	-	46.5	62	nC
Q_{gs}	Gate-source charge			13.3		nC
Q_{gd}	Gate-drain charge			17.5	22.5	nC

1. Pulsed: Pulse duration = 300 µs, duty cycle 1.5.

Table 6. Switching times

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-on delay time	V_{DD} = 50V, I_D = 25A R_G = 4.7Ω V_{GS} = 10V *(see Figure 14)*	-	21	-	ns
t_r	Rise time			46		ns
$t_{d(off)}$	Turn-off-delay time		-	54	-	ns
t_f	Fall time			13		ns

Table 7. Source drain diode

Symbol	Parameter	Test conditions	Min.	Typ.	Max	Unit
I_{SD}	Source-drain current		-		80	A
I_{SDM} (1)	Source-drain current (pulsed)		-		320	A
V_{SD} (2)	Forward on voltage	I_{SD} = 50A, V_{GS} = 0	-		1.5	V
t_{rr} Q_{rr} I_{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	I_{SD} = 50A, V_{DD} = 25V di/dt = 100A/µs, T_j = 150°C *(see Figure 16)*	-	80 250 6.4		ns nC A

1. Pulse width limited by safe operating area.
2. Pulsed: Pulse duration = 300 µs, duty cycle 1.5%

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area for TO-220

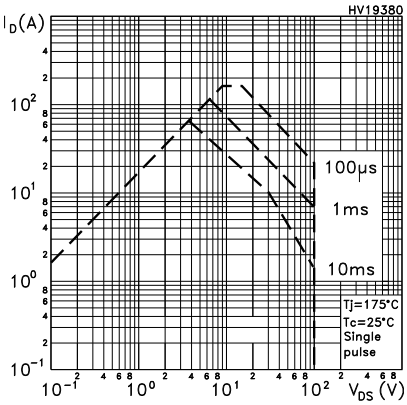


Figure 3. Thermal impedance for TO-220

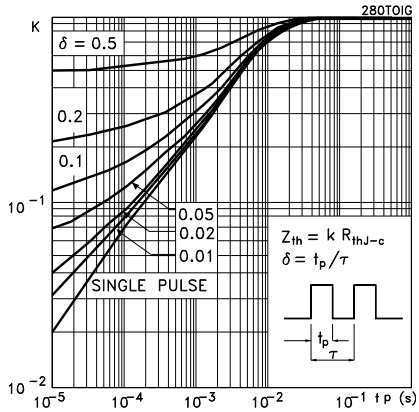


Figure 4. Output characteristics

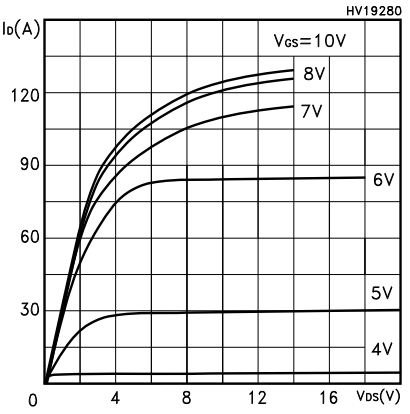


Figure 5. Transfer characteristics

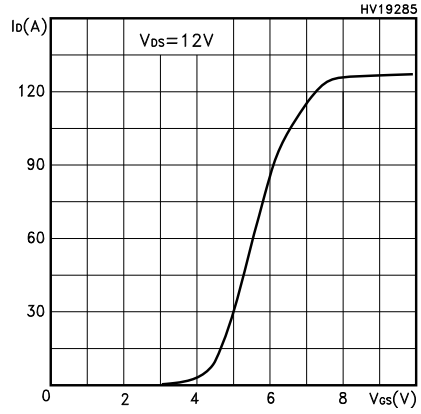


Figure 6. Transconductance

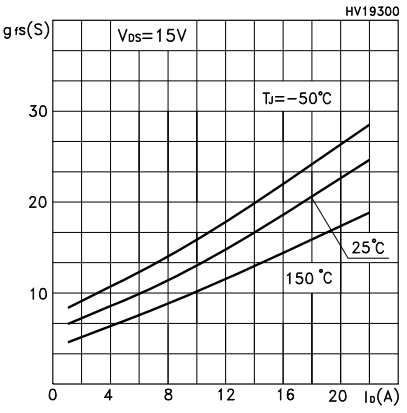


Figure 7. Static drain-source on resistance

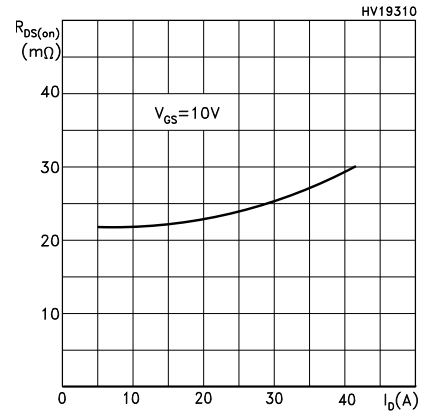


Figure 8. Gate charge vs. gate-source voltage

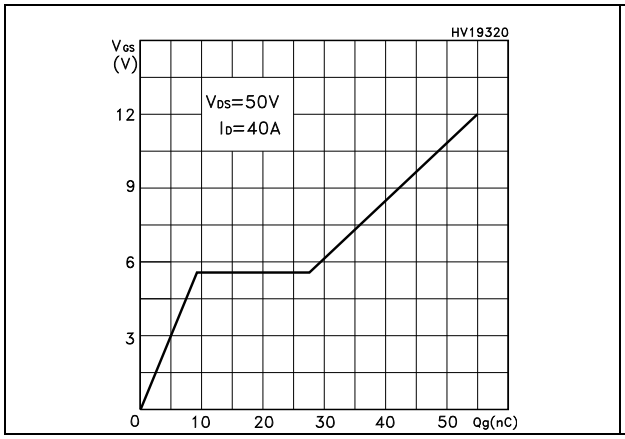


Figure 9. Capacitance variations

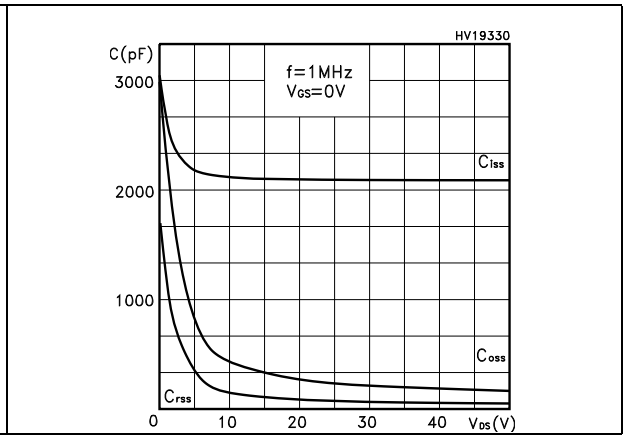


Figure 10. Normalized gate threshold voltage vs. temperature

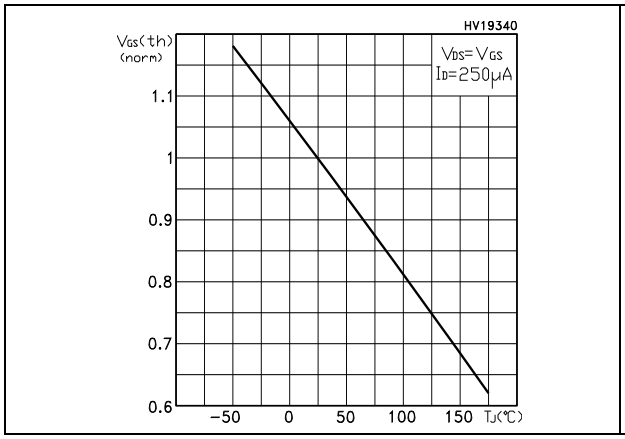


Figure 11. Normalized on resistance vs. temperature

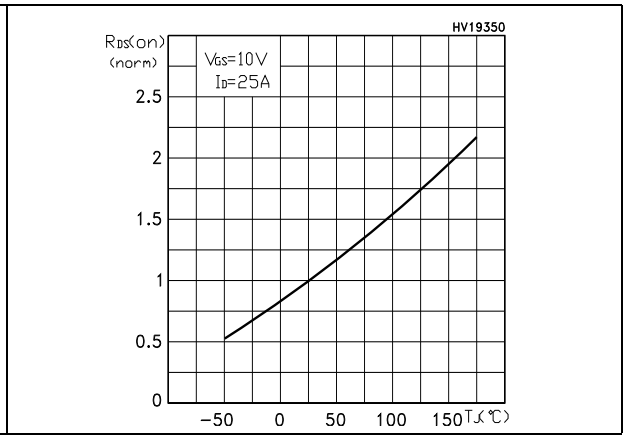


Figure 12. Source-drain diode forward characteristics

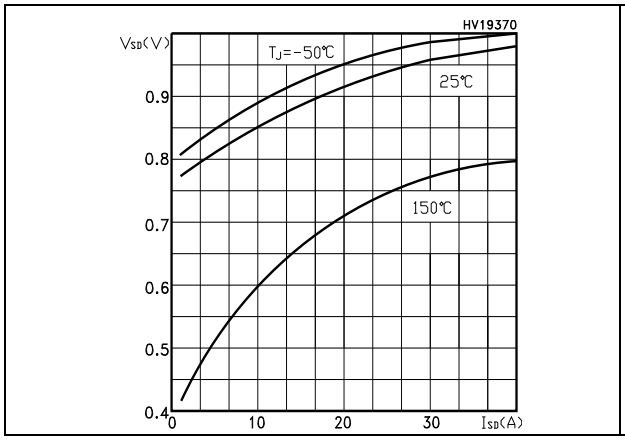
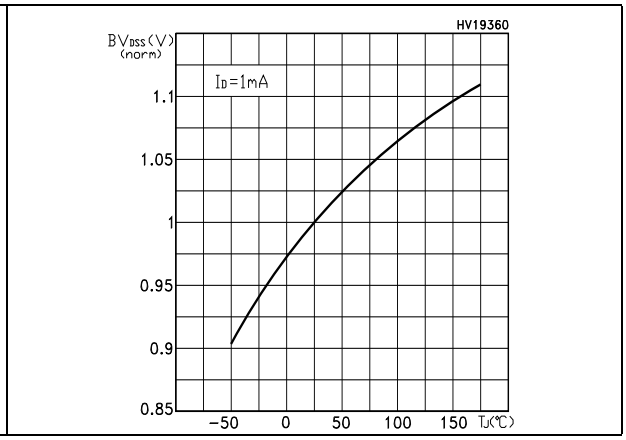


Figure 13. Normalized breakdown voltage vs. Tj



3 Test circuit

Figure 14. Switching times test circuit for resistive load

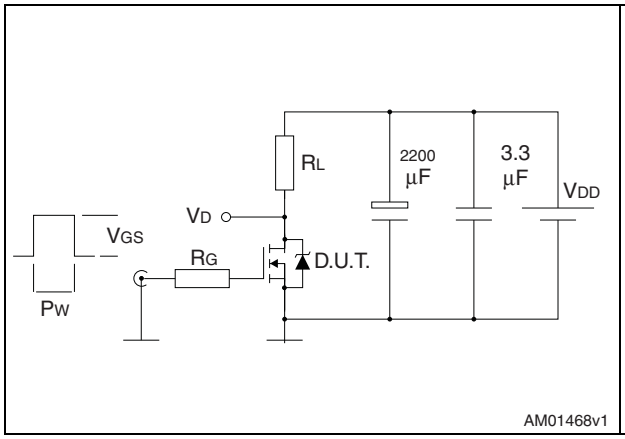


Figure 15. Gate charge test circuit

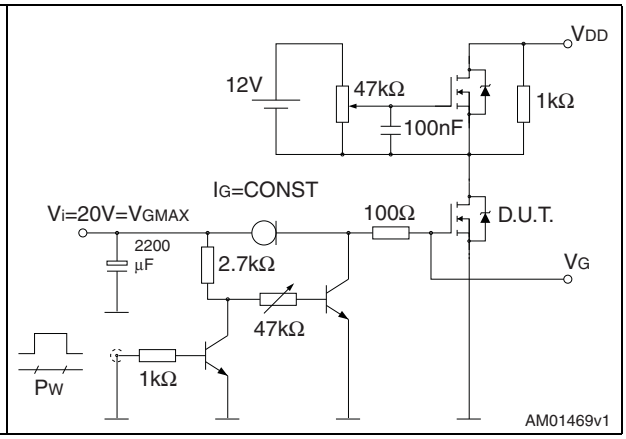


Figure 16. Test circuit for inductive load switching and diode recovery times

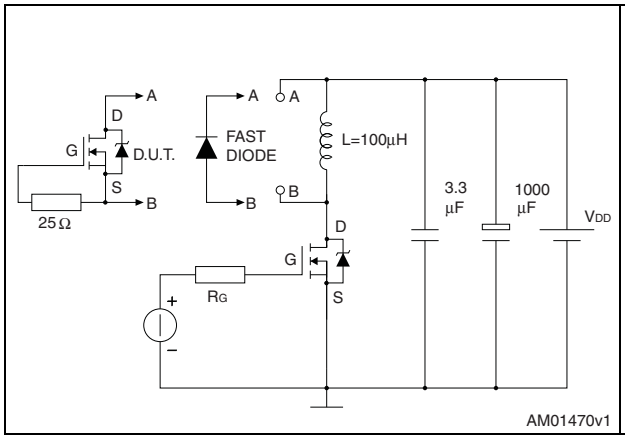


Figure 17. Unclamped Inductive load test circuit

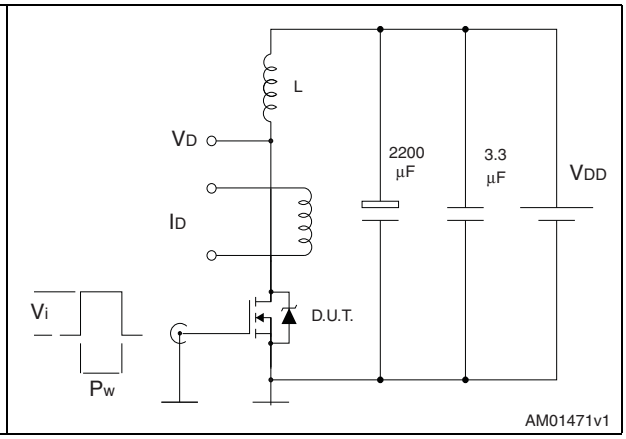


Figure 18. Unclamped inductive waveform

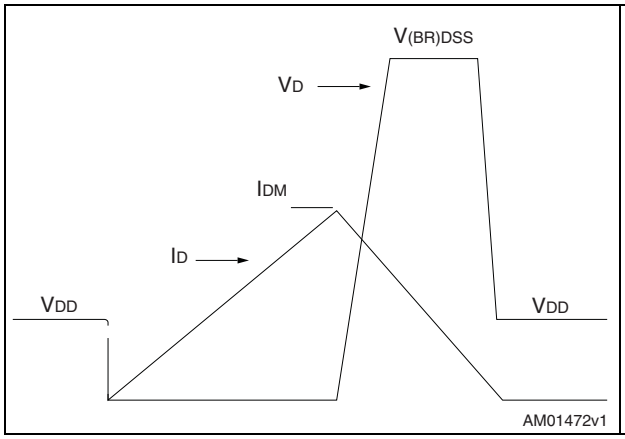
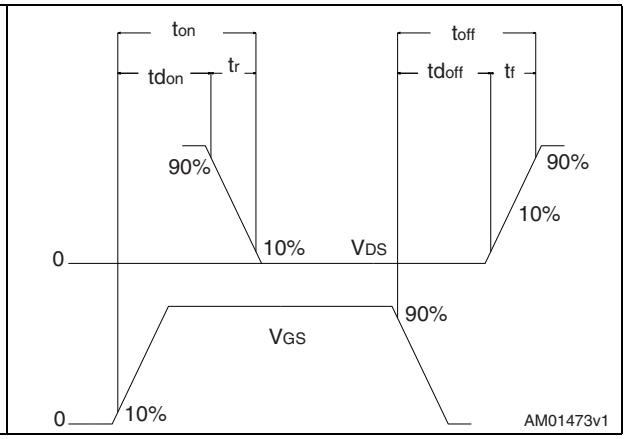


Figure 19. Switching time waveform

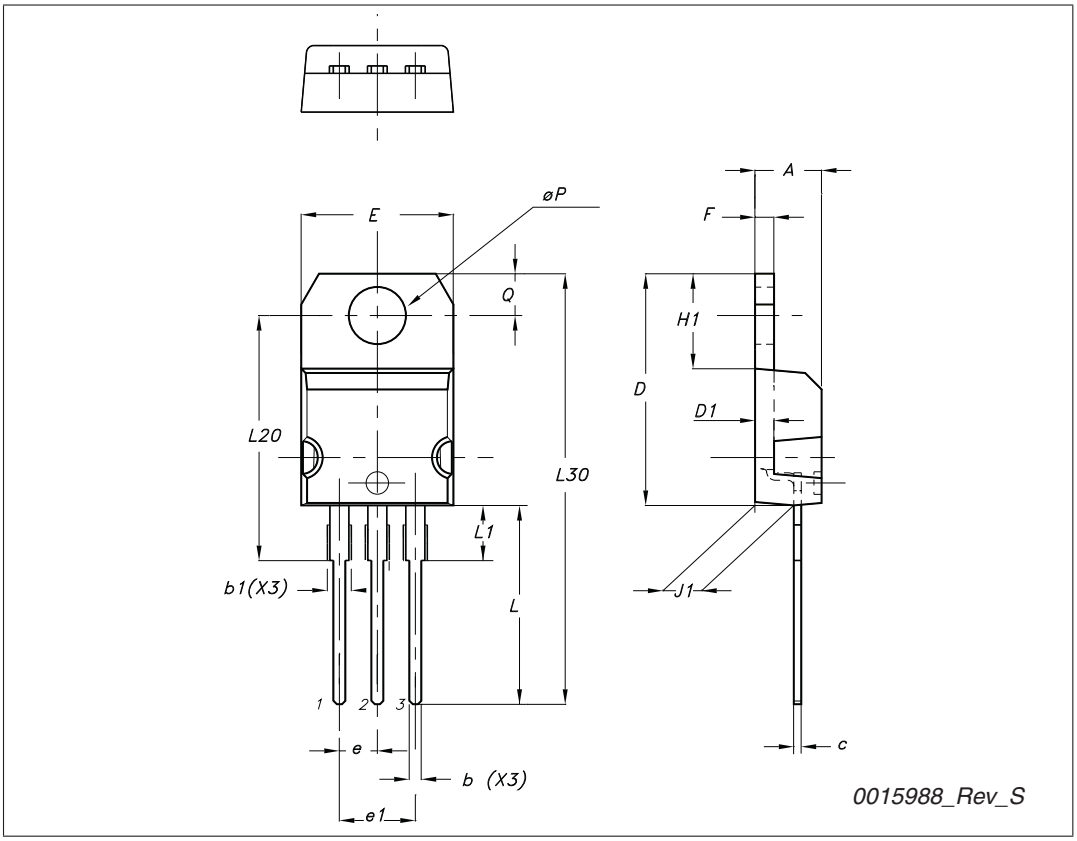


4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

TO-220 type A mechanical data

Dim	mm		
	Min	Typ	Max
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
c	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
e	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
∅P	3.75		3.85
Q	2.65		2.95



5 Revision history

Table 8. Document revision history

Date	Revision	Changes
16-Dec-2004	1	First version.
17-Aug-2006	2	The document has been reformatted.
31-Jan-2007	3	Typo mistake on *Table 2*.
19-Sep-2007	4	Added DPAK.
10-Nov-2010	5	Removed DPAK.

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